NSN 5961-01-111-4724

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-111-4724

Inclosure Material:

Metal

Overall Length:

1.572 inches

Overall Height:

Between 0.250 inches and 0.450 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

400.0 collector to base voltage, dc and 300.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc

Current Rating Per Characteristic:

Between 10.00 amperes source cutoff current and 40.00 amperes source cutoff current

Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

81755-c8646 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0